

PJW3P10A

100V P-Channel Enhancement Mode MOSFET

Voltage

-100 V

Current

-2.6 A

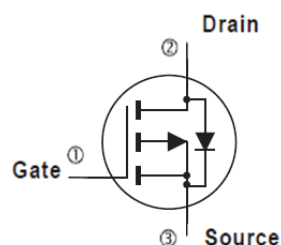
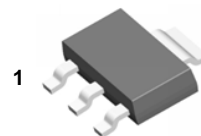
Features

- $R_{DS(ON)}$, $V_{GS}@-10V, I_D@-2.6A < 210m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V, I_D@-1A < 230m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-223 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.043 ounces, 0.123grams
- Marking : W3P10A

SOT-223



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-100	V
Gate-Source Voltage		V _{GS}	±20	V
Continuous Drain Current	T _A =25°C	I _D	-2.6	A
	T _A =70°C		-2.0	
Pulsed Drain Current ^(Note 1)		I _{DM}	-10.4	A
Power Dissipation	T _A =25°C	P _D	3.1	W
	T _A =70°C		2	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal resistance		R _{θJA}	40.3	°C/W
- Junction to Ambient ^(Note 5)				

- Limited only By Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-100	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1.0	-1.9	-3.0	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-2.6A	-	170	210	mΩ
		V _{GS} =-4.5V, I _D =-1A	-	190	230	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-100V, V _{GS} =0V	-	-	-1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 6)						
Total Gate Charge	Q _g	V _{DS} =-80V, I _D =-2.6A, V _{GS} =-10V (Note 1,2)	-	20	-	nC
Gate-Source Charge	Q _{gs}		-	3.5	-	
Gate-Drain Charge	Q _{gd}		-	4.6	-	
Input Capacitance	C _{iss}	V _{DS} =-25V, V _{GS} =0V, f=1.0MHZ	-	1419	-	pF
Output Capacitance	C _{oss}		-	89	-	
Reverse Transfer Capacitance	C _{rss}		-	45	-	
Turn-On Delay Time	td(on)	V _{DS} =-50V, ID=-2.6A, V _{GS} =-10V, R _G =25Ω (Note 1,2)	-	18	-	ns
Turn-On Rise Time	t _r		-	8	-	
Turn-Off Delay Time	td(off)		-	100	-	
Turn-Off Fall Time	t _f		-	30	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	-2.6	A
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.75	-1.2	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. Repetitive rating, pulse width limited by junction temperature $T_J(\text{MAX})=150^{\circ}\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^{\circ}\text{C}$.
5. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

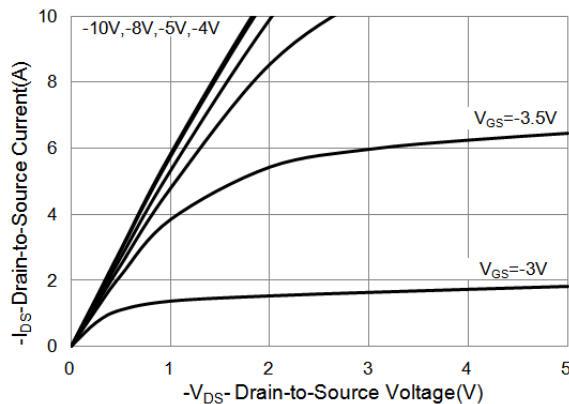


Fig.1 Output Characteristics

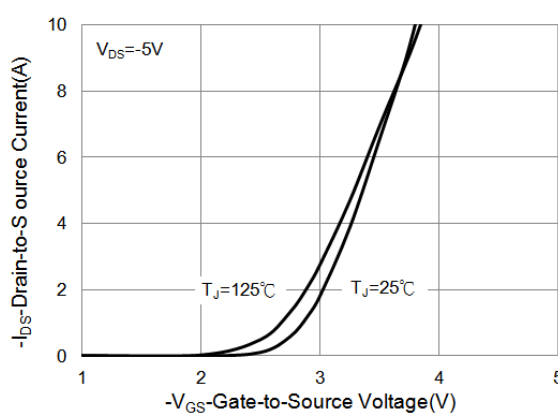


Fig.2 Transfer Characteristics

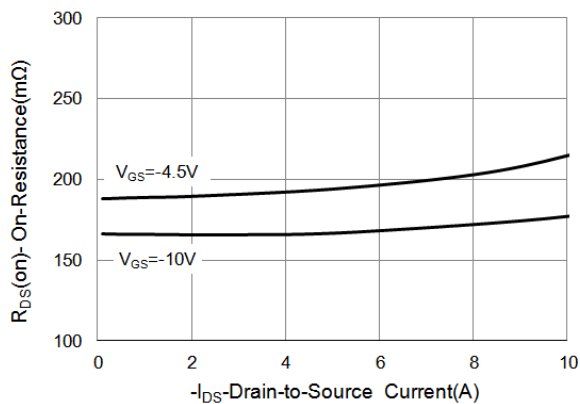


Fig.3 On-Resistance vs. Drain Current

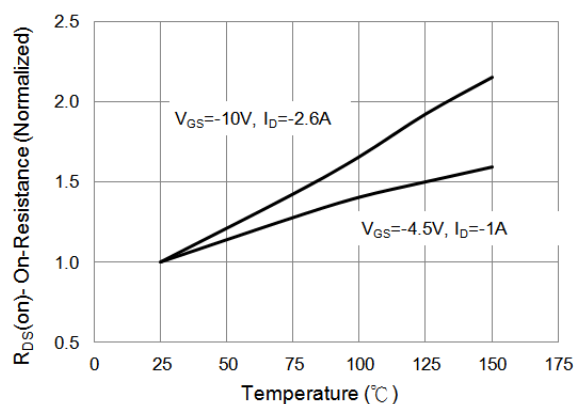


Fig.4 On-Resistance vs. Junction temperature

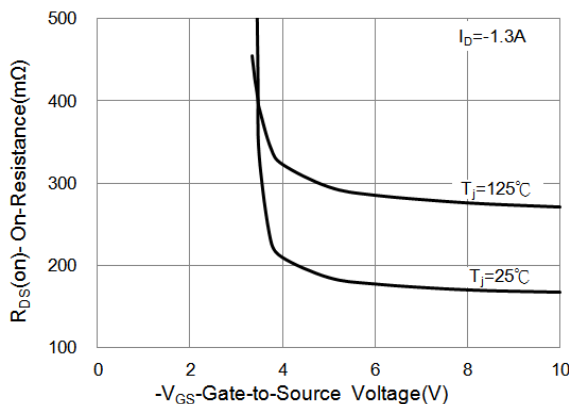


Fig.5 On-Resistance Variation with V_GS.

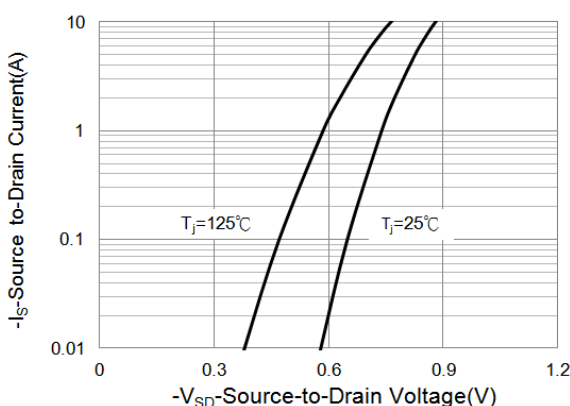
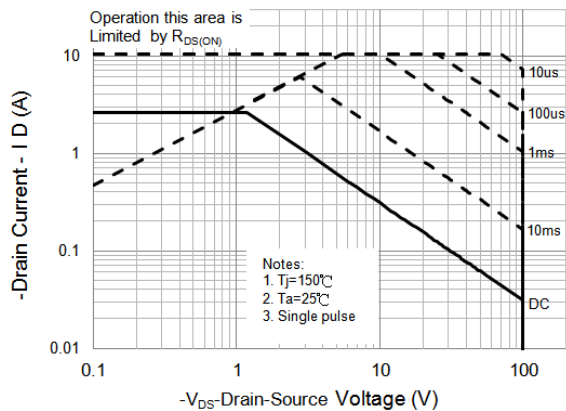
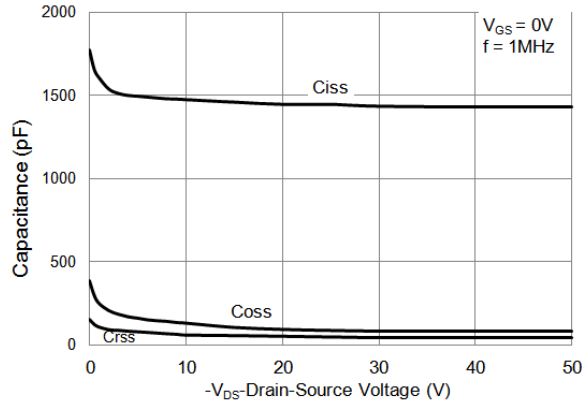
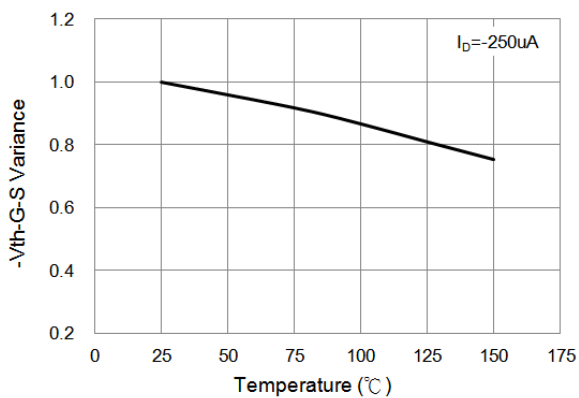
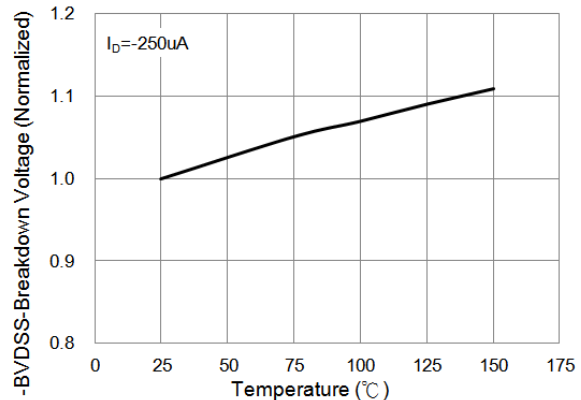
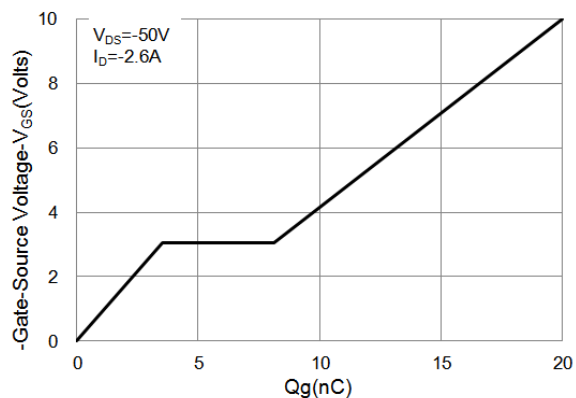


Fig.6 Source-Drain Diode Forward Voltage

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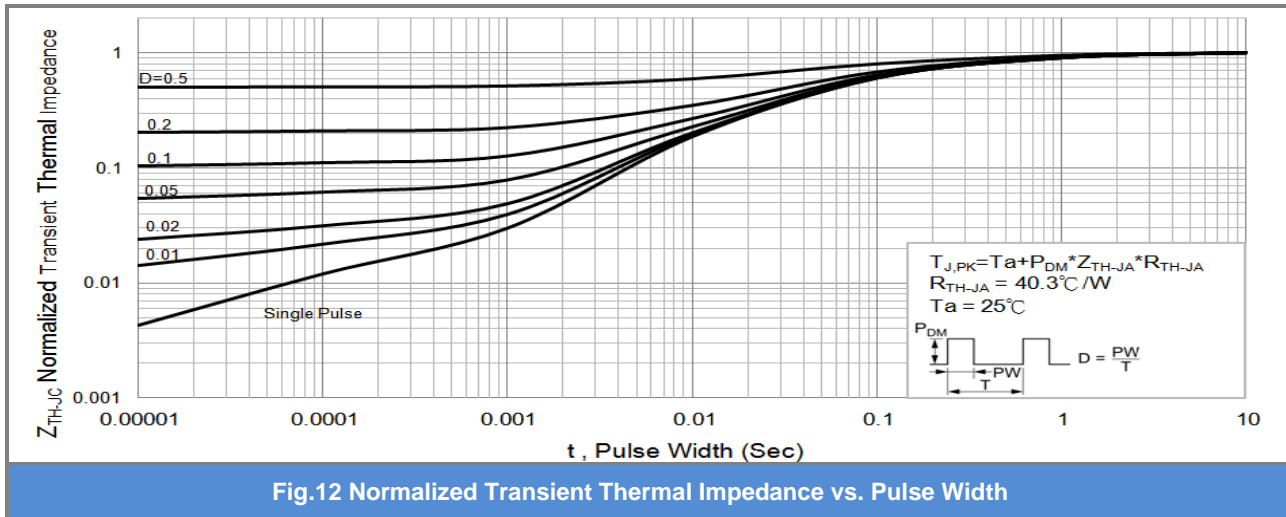
TYPICAL CHARACTERISTIC CURVES





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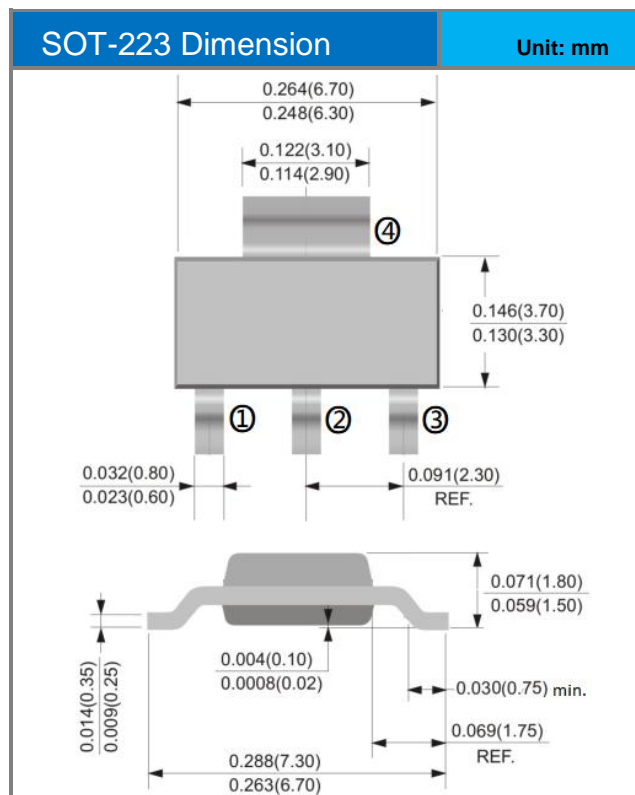
TYPICAL CHARACTERISTIC CURVES





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Packaging Information

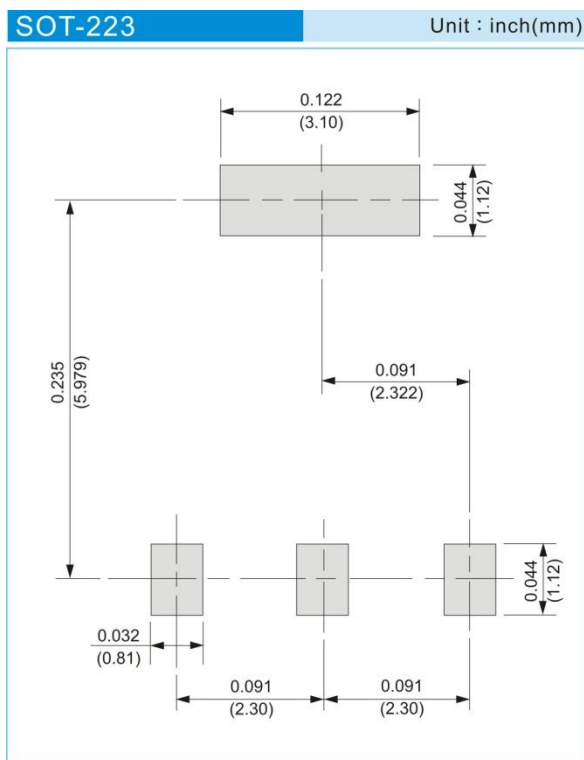


PJW3P10A

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJW3P10A_R2_00001	SOT-223	2,500pcs / 13" reel	W3P10A	Halogen free

MOUNTING PAD LAYOUT





PJW3P10A

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